NSN 5961-01-008-2610

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-008-2610 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.092 inches **Overall Diameter:** 0.120 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 66.2 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 microamperes forward current, average major **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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